## NSN 5962-01-266-8054



Memory Microcircuit - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5962-01-266-8054 **Body Length:** Between 1.440 inches and 1.500 inches **Body Width:** Between 0.510 inches and 0.550 inches **Body Height:** Between 0.145 inches and 0.165 inches **Maximum Power Dissipation Rating:** 525.0 milliwatts **Operating Tempurature Range:** -0.0/+70.0 degrees celsius Storage Tempurature Range: -65.0/+125.0 degrees celsius **Features Provided:** Electrostatic sensitive and ultraviolet erasable and w/enable and programmable **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Metal oxide-semiconductor logic **Input Circuit Pattern:** 17 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 13.5 volts power source **Time Rating Per Chacteristic:** 250.00 nanoseconds propagation delay time, low to high level output and 250.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 28 printed circuit Shelf Life: N/a **Unit Of Measure:** 

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**Demilitarization:** Yes - demil/mli